# 2SD1645

### Silicon NPN epitaxial planar type darlington

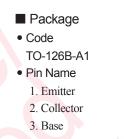
For low frequency amplification

#### Features

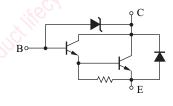
- Built-in zener diode (60 V) between collector-base and collector-emitter
- Small variation in withstand pressure
- Darlington connection
- Extremely satisfactory linearity of the forward current transfer ratio  $h_{FE}$

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	60±10	V	
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	60±10	V	
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	5	V	
Collector current	I <sub>C</sub>	1.0	Α	
Peak collector current	I <sub>CP</sub>	1.5	Α	
Collector power dissipation	P <sub>C</sub>	1.2	W	
		5.0 *		
Junction temperature	Tj	150	°C	
Storage temperature	T <sub>stg</sub>	-55 to +150	s°C	



#### Internal Connection



Note) \*: With a 100 mm × 100 mm × 2 mm Al heat sink at  $T_a = 25^{\circ}C$ 

#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	$I_{\rm C} = 100 \ \mu {\rm A}, I_{\rm E} = 0$	50		70	V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{\rm C} = 1 \text{ mA}, I_{\rm B} = 0$	50		70	V
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	$I_{\rm E} = 100 \mu {\rm A}, I_{\rm C} = 0$	5			V
Collector-base cutoff current (Emitter open)	I <sub>CBO</sub>	$V_{CB} = 25 \text{ V}, I_E = 0$			1	μΑ
Emitter-base cutoff current (Collector open)	I <sub>EBO</sub>	$V_{EB} = 4 \text{ V}, I_{C} = 0$			1	μΑ
Forward current transfer ratio *1	h <sub>FE</sub> *2	$V_{CE} = 10 \text{ V}, I_C = 1.0 \text{ A}$	4000		40 000	
Collector-emitter saturation voltage *1	V <sub>CE(sat)</sub>	$I_{\rm C} = 1.0 \rm{A}, I_{\rm B} = 1.0 \rm{mA}$			1.8	V
Base-emitter saturation voltage *1	V <sub>BE(sat)</sub>	$I_{\rm C} = 1.0 \rm{A}, I_{\rm B} = 1.0 \rm{mA}$			2.2	V
Transition frequency	f <sub>T</sub>	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		150		MHz

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

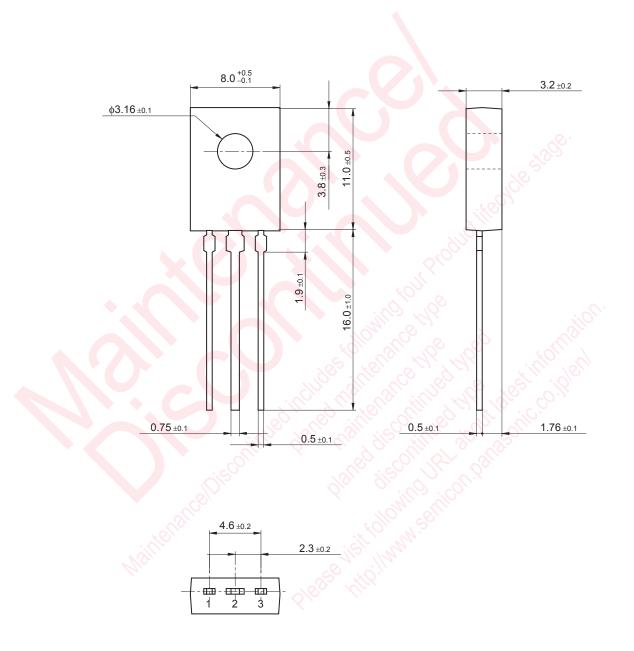
2. \*1: Pulse measurement

\*2: Rank classification

Rank	Q	R	S
$h_{\rm FE}$	4000 to 10000	8000 to 12000	16000 to 40000

TO-126B-A1

Unit: mm



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